





# 深圳市强生光电科技有限公司

Shenzhen JNJ Optoelectronics Co., Limited

## 产品规格书

SPECIFICATION FOR APPROVAL

客户名称 Customer	
样品名称 Description	3427 传感器
产品型号 Part No	JNJ-ITR8307
产品料号 Product No	
版本 Revision	A/1
制作日期 Date	2023-12-26

制作 Producer	工程部 Engineering Dept.	业务部 Business department	批准 Approval
			
客户承认结果 Customer acknowledges Results			

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## 外观 Exterior:



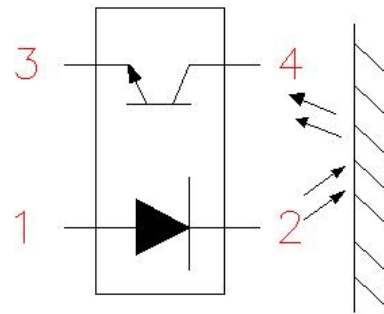
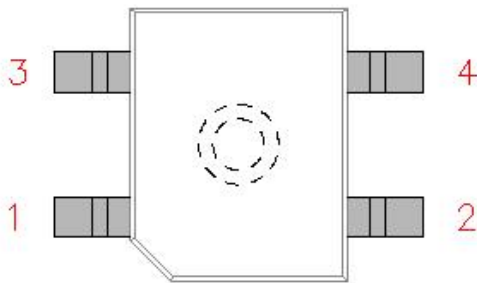
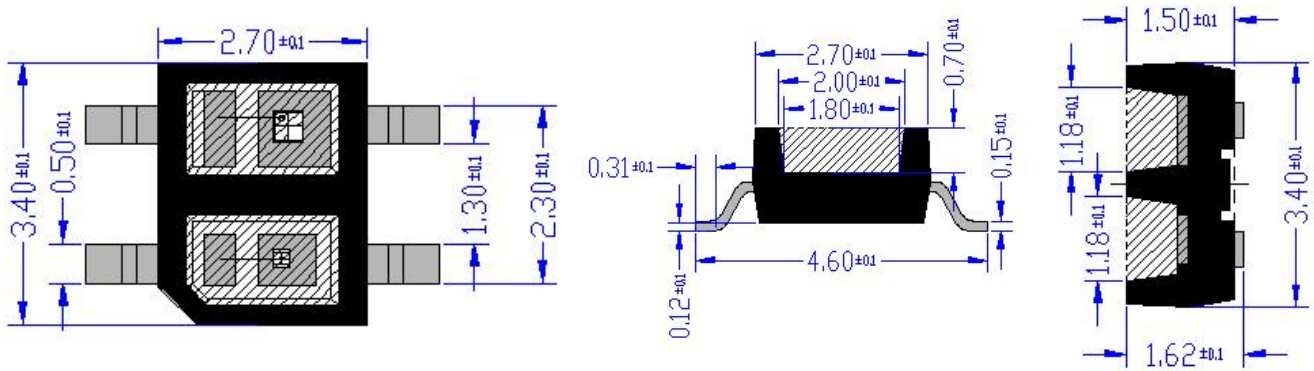
## 产品构造 Product conformation:

- 封装胶水: 环氧液态硅  
Packaging glue: Epoxy liquid silica gel
- 封装支架: 3427 支架  
Packaging bracket: 3427 holder
- 发光颜色: 红外(不可见光) 波长 940nm+PT  
Luminous color: Infrared (invisible light) wavelength 940nm+PT
- 芯片规格: 9mil\*9mil+16mil\*16mil  
Chip specification: 9mil\*9mil+16mil\*16mil
- 静电敏感材质  
Electrostatic sensitive material

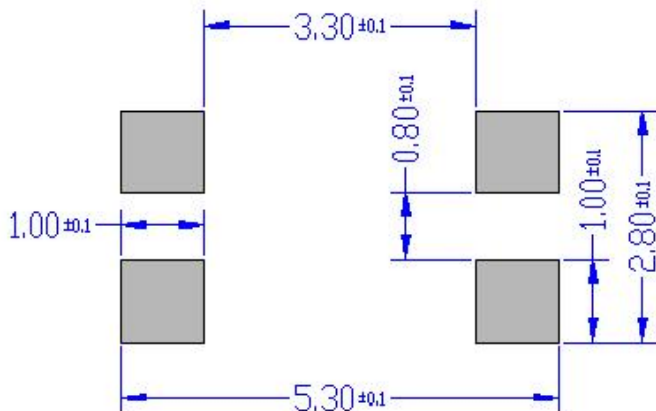


## 应用 Applications:

- 照相机、摄影机 Camera.
- 录像机 VCR.
- 软盘驱动器 Floppy disk driver.
- 盒式录音机 Cassette type recorder.
- 各种微电脑控制设备 Various microcomputer control equipment.

**产品外形尺寸 Package outline dimensions:**


焊盘建议大小 Recommended size of pad



焊点结构 Pad Configuration:

焊点 Pad	功能 Function
1	正极 Anode
2	负极 Cathode
3	发射极 Emitter
4	集电极 Collector

**备注(Note):**

- 标注尺寸单位为毫米  
Dimensions are in millimeters.
- 除特别标注外, 所有尺寸允许公差 $\pm 0.1\text{mm}$ 。  
Tolerances unless mentioned are  $\pm 0.1\text{mm}$ .

**极限参数 AbsoluteMaximumRatingsat:**

参数 Parameter		符号 Symbol	额定值 Rating	单位 Unit
输入 Input	正向电流 Forward current	I <sub>F</sub>	50	mA
	反向电压 Reverse voltage	V <sub>R</sub>	5	V
	功耗 Power dissipation	P <sub>d</sub>	75	mW
	脉冲电流 Peak Forward Current (Pulse Width ≤100uS, Duty Cycle =1%)	I <sub>FP</sub>	500	mA
输出 Output	集电极-发射极电压 Collector-emitter voltage	V <sub>CEO</sub>	35	V
	发射极-集电极电压 Emitter-collector voltage	V <sub>ECO</sub>	6	V
	集电极电流 Collector current	I <sub>c</sub>	20	mA
	集电极功耗 Collector power dissipation	P <sub>c</sub>	75	mW
工作温度 Operating temperature		T <sub>opr</sub>	-25~+85	°C
存储温度 Storage temperature		T <sub>stg</sub>	-40~+100	°C
焊接温度 soldering temperature (1/16 inch from body for 5 seconds)		T <sub>sol</sub>	260	°C

**光电特性参数 Electro-optical Characteristics:**

参数 Parameter		符号 Symbol	测试条件 Conditions	最小 Min	平均 Typ	最大 Max	单位 Unit	
Input	Forward Voltage	V <sub>F</sub>	I <sub>F</sub> =20mA	1.0	1.2	1.5	V	
	Reverse Current	I <sub>R</sub>	V <sub>R</sub> =6V	-	-	10	μA	
	Peak Wavelength	λ <sub>P</sub>	I <sub>F</sub> =20mA	-	940	-	nm	
Output	Collector Dark Current	I <sub>CEO</sub>	V <sub>CE</sub> =20V	-	10 <sup>-9</sup>	10 <sup>-7</sup>	A	
Transfer Charact- eristics	* 1 Collector Current		I <sub>c</sub>	V <sub>CE</sub> =2V I <sub>F</sub> =4mA	10	-	400	μA
	* 2 Leak Current		I <sub>LEAK</sub>	V <sub>CE</sub> =2V I <sub>F</sub> =4mA	-	-	0.1	μA
	Response time	Rise time	t <sub>r</sub>	V <sub>CE</sub> =2V I <sub>c</sub> =100μA	-	20	100	μsec
		Fall time	t <sub>f</sub>	R <sub>L</sub> =1KΩ,d=1mm	-	20	100	μsec

**备注(Note):**

- \* 1. 反射对象的条件和布置如下所示。  
\* 1. The condition and arrangement of the reflective object are shown below.
- \* 2. 不反光的物体。  
\* 2. Without reflective object.
- 以上所示电压测量误差±0.1v  
The voltage measurement error shown above is ±0.1v
- 以上所示波长测量误差±1nm  
The above wavelength measurement error is ±1nm

**辐射通量分类表 Classification table of radiant flux:**

Test Condition and Arrangement for Collector Current

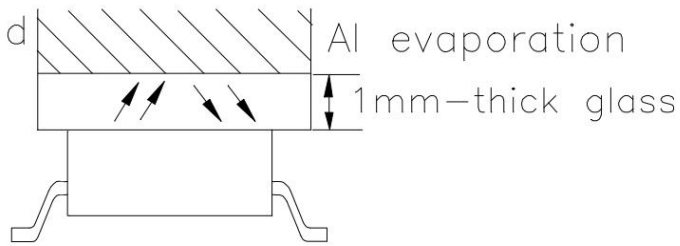


Fig. 1 Forward Current vs. Forward Voltage

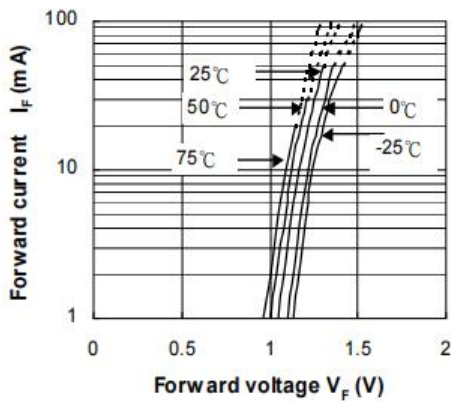


Fig. 3 Collector Current vs. Collector-emitter Voltage

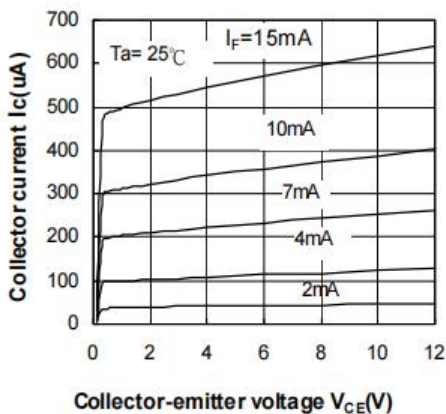


Fig. 2 Collector Current vs. Forward Current

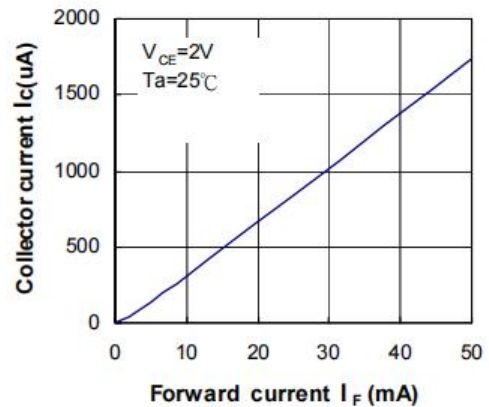


Fig. 4 Relative Collector Current vs. Ambient Temperature

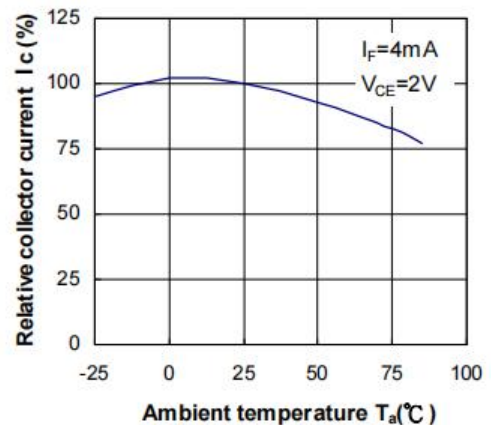
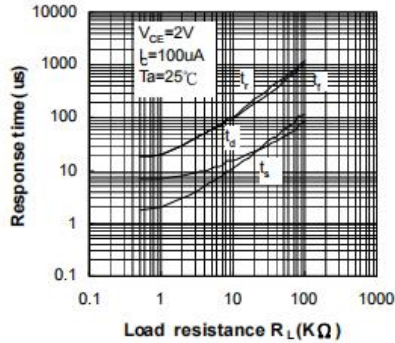


Fig. 5 Response Time vs. Load Resistance



Test Circuit for Response Time

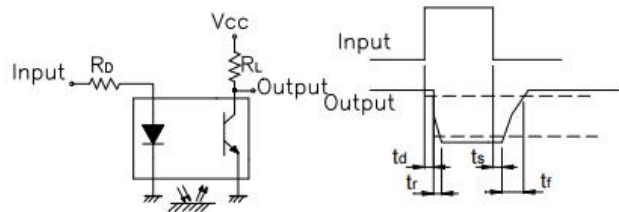


Fig. 6 Collector Dark Current vs. Ambient Temperature

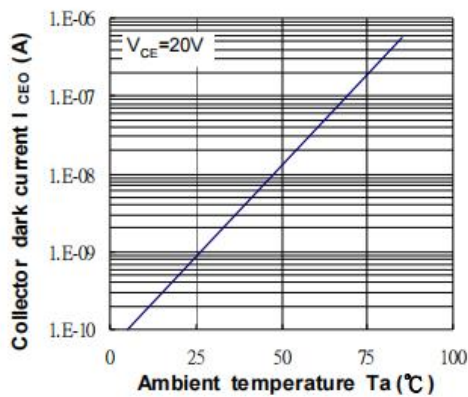


Fig. 7 Relative Collector Current vs. Distance between Sensor and Al Evaporation Glass

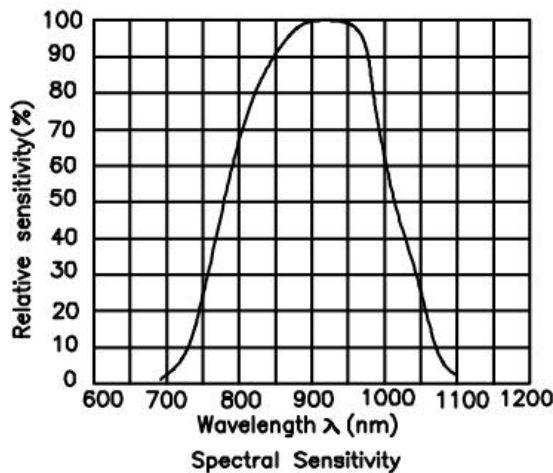
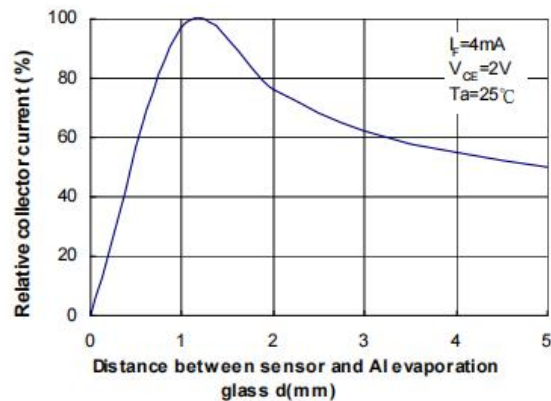
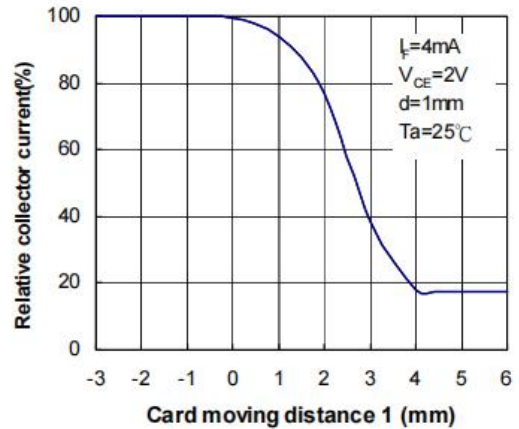
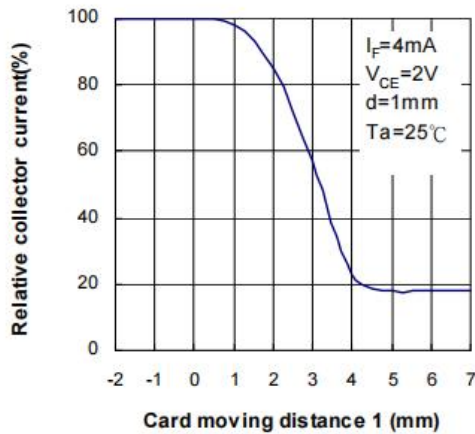


Fig. 8 Relative Collector Current vs. Card Moving Distance (1)      Fig. 9 Relative Collector Current vs. Card Moving Distance (2)



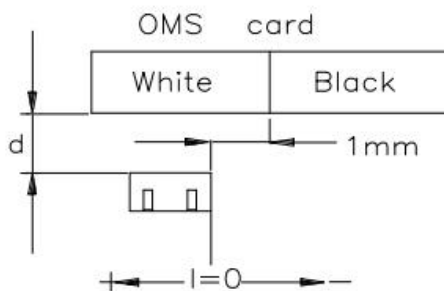
### Test Condition for Distance & Detecting Position Characteristics

Correspond to Fig. 7



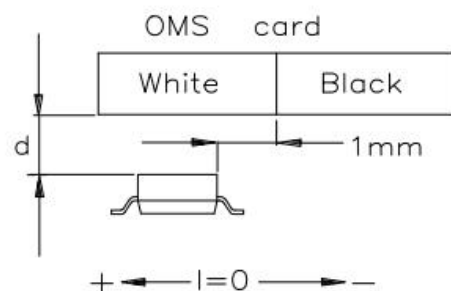
Correspond to Fig. 8  
Test condition

$I_F=4mA$   
 $V_{CE}=2V$   
 $d=1mm$

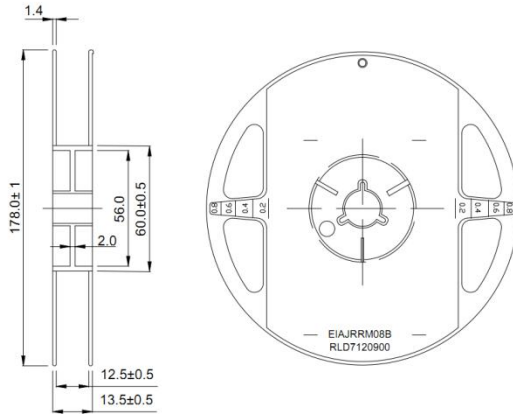


Correspond to Fig. 9  
Test condition

$I_F=4mA$   
 $V_{CE}=2V$   
 $d=1mm$

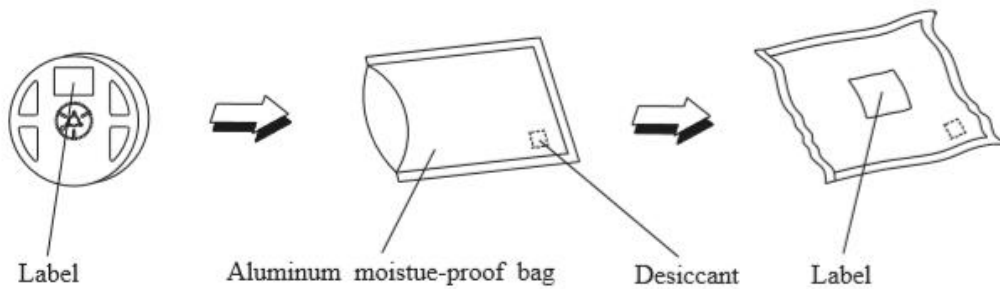
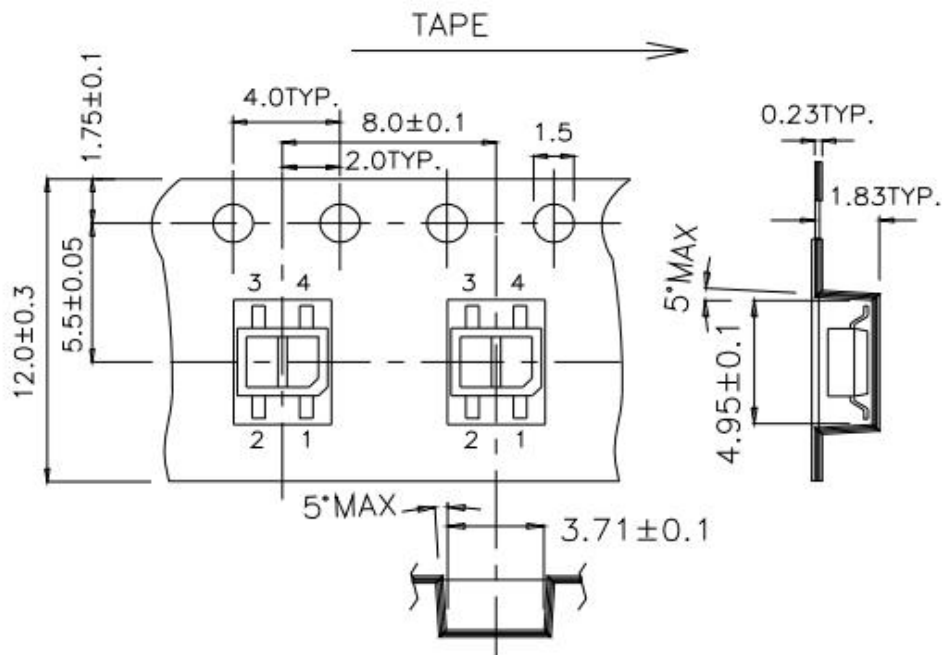


**卷轴尺寸 Reel Dimensions:**



**使用方向及尺寸 Progressive direction and Dimensions:**

**Loaded quantity 1000PCS per reel**





## 应用注意事项 Application precautions:

### 保存及使用 Preservation and use:

1. 在打开包装前, LED 应存放在 30°C/60%RH 或以下的环境中。打开包装后, LED 应置于 20-30°C/30%RH 或以下的环境中使用。  
Before opening the package, the LED should be stored at 30°C/60%RH or less. After opening the package, the LED should be placed in an environment of 20-30°C/30%RH or less.
2. molding 封装及 SMD LED 开封后要在 24H 之内使用, 为了避免环境的影响, 建议拆封后, 经过 80°C/24H 除湿, 没用完 LED 需及时做抽真空包装处理, 避免再次使用时发生失效。  
To avoid the impact of the environment, it is recommended to dehumidify after unpacking at 80°C/24H. All the leds are needed to be vacuumed to avoid failure
3. 若干燥剂褪色或过期使用, 需干燥烘烤: 80±5°C/24 小时。  
If the desiccant faded or expired use, dry baking: 80±5°C/24 hours.
4. LED 的胶表面易沾灰尘, 需要做好相关防尘措施。  
LED Glue surface easy to dust, need to do the relevant dust prevention measures.

### 取放 pick and place

夹取 LED 时只能触及支架体, 镊子之类的工具不要对透镜施压。更不要刺或推透镜。

When taking the LED, you should only touch the bracket. Tools such as tweezers should not put pressure on the lens. Don't stab or push the lens.

### 热量处理 Heat treatment

在过大电流驱动时 LED 的 Tj (节点温度) 会超过限制值, 这导致 LED 的寿命严重缩短, 热量处理措施要有效的减小应用产品的热阻。比较通用的做法: 把 LED 封装器件安装在金属基质的 PCB 板上。1W LED 产品要求金属基板的表面散热面积至少 30cm<sup>2</sup> (3W 产品建议 80cm<sup>2</sup> 以上), 且其导热系数要高于 2.0W/mK。LED 和金 属基板结合靠导热性较好的导热胶, 要求导热系数高于 1.0W/mK, 厚度小于 100um。

When driven by excessive current, the Tj (node temperature) of LED will exceed the period limit value, which leads to a serious shortening of LED life. Thermal treatment measures should effectively reduce the thermal resistance of application products. Common practice: install LED packages on metal matrix PCB boards. 1W LED products require the surface heat dissipation area of the metal substrate to be at least 30cm squared (over 80cm squared is recommended for 3W products), and its thermal conductivity is higher than 2.0w /mK. LED and gold substrate are combined by thermal conductive adhesive with good thermal conductivity. The thermal conductivity coefficient is required to be higher than 1.0w /mK and the thickness is less than 100um.

### 清洁 Clean

需要清洁的话, 用干净的软碎布沾点酒精轻力擦除异物, 不可以采用诸如丙酮之类的清洁剂以免可能造成腐蚀破坏。

If you need to clean, use a clean, soft cloth dipped in alcohol to gently remove foreign matter. Do not use a cleaner such as acetone to avoid possible corrosion damage.

### 电性注意事项 Electrical precautions

1. LED 不允许反向驱动。  
Led Reverse drive is not allowed
2. 限流措施是必要的, 否则轻微的电压变化会导致较大的电流变化, 可能造成 LED 失效。  
Current limiting measures are necessary, otherwise slight voltage changes will lead to large current changes, which may lead to LED failure.
3. 在发光量满足要求的前提下, 推荐采用低于额定电流的驱动电流, 这样有利于提高产品的可靠性。  
Under the premise that the luminous quantity meets the requirements, it is recommended to use the drive current lower than the rated current, which is conducive to improving the reliability of the product.

### 防静电措施 anti-static precautions

LED 是静电敏感器件, 在保存、使用过程中要采取防静电措施。静电和电涌会导致产品特性发生改变, 例如正向电压降低等, 情况严重甚至会损毁产品。所以对于整个工序(生产, 测试, 包装等)与 LED 直接接触的员工都要做好防止和消除静电的措施。所有相关的设备和机器都应该正确接地。接地交流电阻小于 1.0 欧姆, 工作台上需垫表面电阻 106-109 欧姆的桌垫。在容易产生静电的环境和设备上, 还必须安装离子风扇。作业过程中, 操作员需使用防静电手环, 防静电垫子, 防静电工作服, 工作鞋, 手套, 防静电容等。

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LED is electrostatic sensitive devices, in the process of preservation, use to take anti-static measures. Static electricity and surge can lead to changes in product characteristics, such as forward voltage reduction, which can be serious and even damage the product. So for the whole process (production, testing, packaging, etc.) and LED direct contact staff should do a good job to prevent and eliminate electrostatic measures. All related equipment and machinery should be properly grounded. The grounding ac resistance is less than 1.0 ohm, the table mat with surface resistance of 10<sup>6</sup>-10<sup>9</sup> ohm is needed on the work table. Ion fans must also be installed in electrostatic environments and equipment. During the operation, the operator should use anti-static bracelet, anti-static mat, anti-static overalls, working shoes, gloves, anti-static capacity.

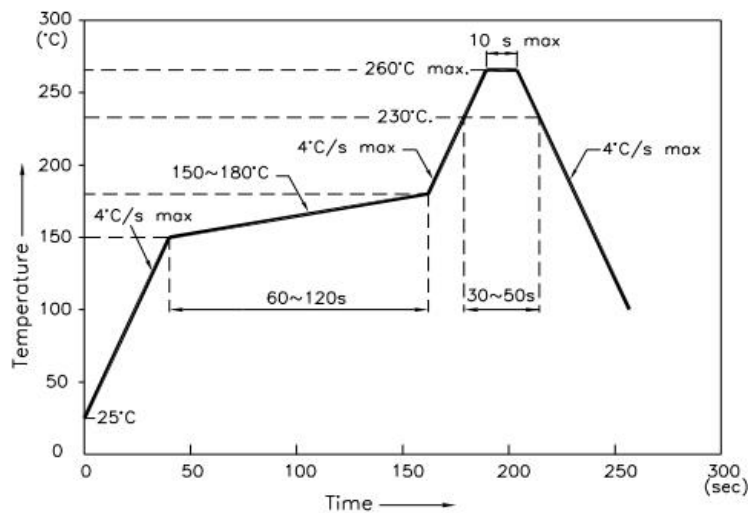
### 电烙铁焊接 An electric soldering iron

建议使用防静电电烙铁，尖端处温度不超过 350℃，每次焊锡时少于 3 秒。电烙铁的功率宜低于 60W。每焊完一次之后间隔 2 秒以上，分别焊好两个电极引脚。焊接时不可对透镜用力施压。LED 如有问题一般都是从焊锡时开始出现。故必须按要求小心作业。

It is recommended to use anti-static electric soldering iron, the temperature at the tip does not exceed 350℃, less than 3 seconds for each soldering. The power of the soldering iron should be less than 60W. Weld two electrode pins more than 2 seconds after each welding. Do not force the lens during welding. Problems with leds usually begin when they are soldered. So you must work carefully as required.

### SMT 回流焊说明 Reflow instructions:

Reflow Soldering Profile For Lead-free SMT Process.



NOTES:

1. We recommend the reflow temperature 245°C (+/-5°C). The maximum soldering temperature should be limited to 260°C.
2. Don't cause stress to the epoxy resin while it is exposed to high temperature.
3. Number of reflow process shall be 2 times or less.

### 注意事项 matters need attention:

1. 回流焊只允许做一次。  
Reflow soldering is only allowed once.
2. 回流焊过程中不要对灯体施加压力。  
Do not apply pressure to the lamp body during reflow
3. 回流焊完成之后不要压挤散热板、不可压到胶体部分。  
After reflow welding is completed, do not press the heat dissipation plate, do not press to the colloidal part.
4. 若有比较低熔点的锡膏，TP 可以适当降低。  
If there is a lower melting point of solder paste, TP can be appropriately reduced.

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